

L Number	Hits	Search Text	DB	Time stamp
1	13	(sic or (silicon adj carbide)) with (dop\$4 or implant\$4) with (energy adj level\$2)	USPAT	2003/06/06 11:18

L Number	Hits	Search Text	DB	Time stamp
1	2	"6459100"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/05 01:45
2	1		USPAT	2003/06/05 01:44
3	107867	sic or (silicon adj carbide)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/05 01:45
5	7	((sic or (silicon adj carbide)) with phosphorus with metal\$2) with (heat\$4 or anneal\$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/05 01:47
6	5	((sic or (silicon adj carbide)) with phosphorus with metal\$2) and diode\$2	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/05 01:51
4	74	(sic or (silicon adj carbide)) with phosphorus with metal\$2	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/05 01:54